

## New performance record for eco-friendly nanocrystal solar cells

ICFO researchers present a post-deposition in situ passivation strategy to reduce surface defects in eco-friendly solution processed nanocrystal ultrathin solar cells. The procedure has led to the highest power conversion efficiency for this type of solar cells recorded to date.

October 23, 2024

In the era of climate change, renewable energies have quickly gained popularity, with solar cells being a prominent example of this shift. For instance, [in 2023, installed solar photovoltaic power increased by 28% in Spain compared to the previous year](#), accounting for 20.3% of Spain's total energy generation pool, a trend that is similarly mirrored in most Western countries. Despite their commercialization and their unquestionable environmental benefits, solar cells still have room for improvement, as they are usually based on materials that are not fully sustainable. Ubiquitous solar harvesting - beyond solar farms - is considered the way to go to power buildings, infrastructures, IoT systems or even vehicles. That would require light-weight, low cost, flexible and eco-friendly based solar cell technology. Th

scientific community is thus directing its efforts toward finding sustainable alternatives that preserve (or even boost) the electricity generation efficiency, reduce costs and simplify the manufacturing efforts of current solar cells.

One promising material that has emerged as an environmentally-friendly alternative is colloidal silver bismuth sulfide (AgBiS<sub>2</sub>) nanocrystal, a material that is characterized by an extremely high absorption coefficient and thus leads to ultra-thin-film absorbers for solar cells. Through a layer-by-layer manufacturing process, solar cells with compelling performance have already been reported. But to minimize material loss, reduce costs and improve manufacturing scalability, the multi-step deposition method must be replaced by a single-step approach.

This can be realized by developing AgBiS<sub>2</sub> nanocrystal inks. Since 2020, several researches in this regard have been reported. However, the resulting AgBiS<sub>2</sub> nanocrystals have still exhibited significant surface defects accompanied by low power conversion efficiency in solar cell, meaning that the techniques aimed at eliminating them -called surface passivation- were not sufficiently effective. The remaining surface defects trapped the electrical charge carriers generated by sunlight and triggered their recombination, reducing the device efficiency to lower levels than those achieved with a layer-by-layer manufacturing procedure.

Therefore, a simpler yet more effective passivation methodology for AgBiS<sub>2</sub> nanocrystal ink is needed to bring the efficiency of eco-friendly solar cells closer to competitive levels.

Recently, ICFO researchers, **Dr. Jae Taek Oh, Dr. Yongjie Wang, Dr. Carmelita Roda, Dr. Debranjana Mandal, Dr. Gaurav Kumar, Dr. Guy Luke Whitworth**, led by **ICREA Prof. Gerasimos Konstantatos**, have taken a significant step forward in this direction. In an *Energy & Environmental Science* article, they have reported on a post-deposition in situ passivation (P-DIP) **strategy that improves surface passivation**, yielding nanocrystal ink films with enhanced optoelectronic properties. The resulting ultrathin solar cells showed higher power conversion efficiency than their multi-step deposition counterparts, setting a **new performance record for eco-friendly nanocrystal solar cells**.

#### **Post-deposition in situ passivation for improved surface passivation**

ICFO researchers managed to effectively passivate surface defects present in their nanocrystal ink film. *Imagine a bumpy road that slows down cars. Surface passivation is like repaving the road, making it smoother so cars can move without getting stuck. In our case, the removal of surface defects is very important to facilitate the transportation of charge carriers created from light absorption in nanocrystal films*, explains Dr. Jae Taek Oh, first author of the article. *With our P-DIP method, charge carriers could move without 'bumping into so many obstacles' within the AgBiS<sub>2</sub> nanocrystals thin film*,

**The mitigation of defects by a proper passivation strategy translated into higher film quality and, thus, higher performance solar cells.** Their efficiency of around 10% exceeded that of previous solar cells based on AgBiS<sub>2</sub> nanocrystals, involving both single-step and

layer-by-layer deposition methods.

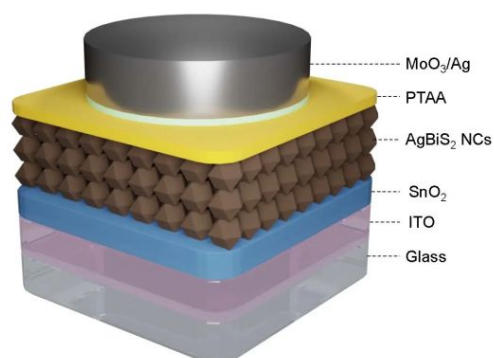
To obtain these outstanding results, the team synthesized the AgBiS<sub>2</sub> nanocrystal ink by introducing a multifunctional molecular agent containing chlorine. Its molecular structure **helped stabilize the nanocrystals and disperse them evenly within the solution**, two crucial factors to ensure smooth coatings. After depositing the film, they carried out additional passivation on the surfaces of AgBiS<sub>2</sub> nanocrystals. This particular in situ passivation strategy **extended the carrier lifetime and balanced carrier transport in the film**, which are also critical aspects to enhance the efficiency of solar cells. **The combination of these effects was the perfect recipe to achieve the unprecedented performance for sustainable solar cells** that ICFO researchers have demonstrated in this study.

**Reference:**

J. T. Oh, Y. Wang, C. Roda, D. Mandal, G. Kumar, G. L. Whitworth, G. Konstantatos. Energy Environ. Sci. (2024). DOI: <https://doi.org/10.1039/D4EE03266G>

**Acknowledgements:**

Results incorporated in this work have received funding from the European Research Council (ERC) under the European Union's Horizon 2020 research and innovation programme (grant agreement No 101002306). We also acknowledge support from the Fundacio Joan Ribas Araquistain (FJRA), the Fundacio Privada Cellex, the program CERCA, EQC2019-005797-P (AEI/FEDER UE), and *Severo Ochoa* Center of Excellence CEX2019-000910-S - Funded by the Spanish State Research Agency.



Schematic of the AgBiS<sub>2</sub> nanocrystal ink solar cell.  
Source: EES.